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ne<mark>x</mark>peria

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Kind regards,

Team Nexperia



1. Product profile

1.1 General description

NPN general-purpose double transistors in a small SOT143B Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package		PNP complement
	NXP	JEITA	
BCV61	SOT143B	-	BCV62
BCV61A			BCV62A
BCV61B			BCV62B
BCV61C			BCV62C

1.2 Features

- Low current (max. 100 mA)
- Low voltage (max. 30 V)
- Matched pairs

1.3 Applications

- Applications with working point independent of temperature
- Current mirrors

2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	collector TR2; base TR1 and TR2	4 3	4 3
2	collector TR1		
3	emitter TR1		
4	emitter TR2	1 2	



006aaa842

3. Ordering information

Table 3. Orde	ring inform	ation					
Type number	Package	Package					
	Name	Description	Version				
BCV61	-	plastic surface-mounted package; 4 leads	SOT143B				
BCV61A							
BCV61B							
BCV61C							

4. Marking

Table 4. Marking codes	
Type number	Marking code ^[1]
BCV61	1M*
BCV61A	1J*
BCV61B	1K*
BCV61C	1L*

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

5. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per trans	istor				
V _{CBO}	collector-base voltage	open emitter	-	30	V
V _{CEO}	collector-emitter voltage	open base	-	30	V
V_{EBS}	emitter-base voltage	$V_{CE} = 0 V$	-	6	V
I _C	collector current		-	100	mA
I _{CM}	peak collector current		-	200	mA
I _{BM}	peak base current		-	200	mA
Per devic	e				
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> -	250	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB).

6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	500	K/W

[1] Device mounted on an FR4 PCB.

7. Characteristics

Table 7. Characteristics

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Transist	or TR1					
I _{CBO}	collector-base cut-off current	V _{CB} = 30 V; I _E = 0 A	-	-	15	nA
		V _{CB} = 30 V; I _E = 0 A; T _j = 150 °C	-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 V;$ $I_{C} = 0 A$	-	-	100	nA
h _{FE}	DC current gain	V_{CE} = 5 V; I_{C} = 100 µA	100	-	-	
		$V_{CE} = 5 V;$ $I_{C} = 2 mA$	110	-	800	
V _{CEsat}	collector-emitter saturation voltage	l _C = 10 mA; l _B = 0.5 mA	-	90	250	mV
		I _C = 100 mA; I _B = 5 mA	-	200	600	mV
V _{BEsat}	base-emitter saturation voltage	I _C = 10 mA; I _B = 0.5 mA	<u>[1]</u> -	700	-	mV
		I _C = 100 mA; I _B = 5 mA	<u>[1]</u> _	900	-	mV
V_{BE}	base-emitter voltage	$I_{C} = 2 \text{ mA};$ $V_{CE} = 5 \text{ V}$	[2] 580	660	700	mV
		I _C = 10 mA; V _{CE} = 5 V	[2] _	-	770	mV
f _T	transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz	100	-	-	MHz
C _c	collector capacitance	$\label{eq:V_CB} \begin{split} V_{CB} &= 10 \text{ V};\\ I_E &= i_e = 0 \text{ A};\\ f &= 1 \text{ MHz} \end{split}$	-	2.5	-	pF
NF	noise figure	$\label{eq:V_CE} \begin{split} V_{CE} &= 5 \ V; \\ I_C &= 200 \ \mu\text{A}; \\ R_S &= 2 \ k\Omega; \\ f &= 1 \ k\text{Hz}; \\ B &= 200 \ \text{Hz} \end{split}$	-	-	10	dB

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Transist	or TR2					
V _{EBS}	emitter-base voltage	V _{CB} = 0 V; I _E = –250 mA	-	-	-1.8	V
		$V_{CB} = 0 V;$ $I_E = -10 \mu A$	-400	-	-	mV
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 2 mA				
	BCV61		110	-	800	
	BCV61A		110	-	220	
	BCV61B		200	-	450	
	BCV61C		420	-	800	
Transist	ors TR1 and TR2					
I _{C1} /I _{E2} 0	current matching	I _{E2} = -0.5 mA; V _{CE1} = 5 V				
		$T_{amb} \le 25 \ ^{\circ}C$	0.7	-	1.3	
		$T_{amb} \le 150 \ ^{\circ}C$	0.7	-	1.3	
I _{E2}	emitter current 2	V _{CE1} = 5 V	[3]	-	-5	mA

Table 7.Characteristics ...continued $T_i = 25$ °C unless otherwise specified.

[1] V_{BEsat} decreases by about 1.7 mV/K with increasing temperature.

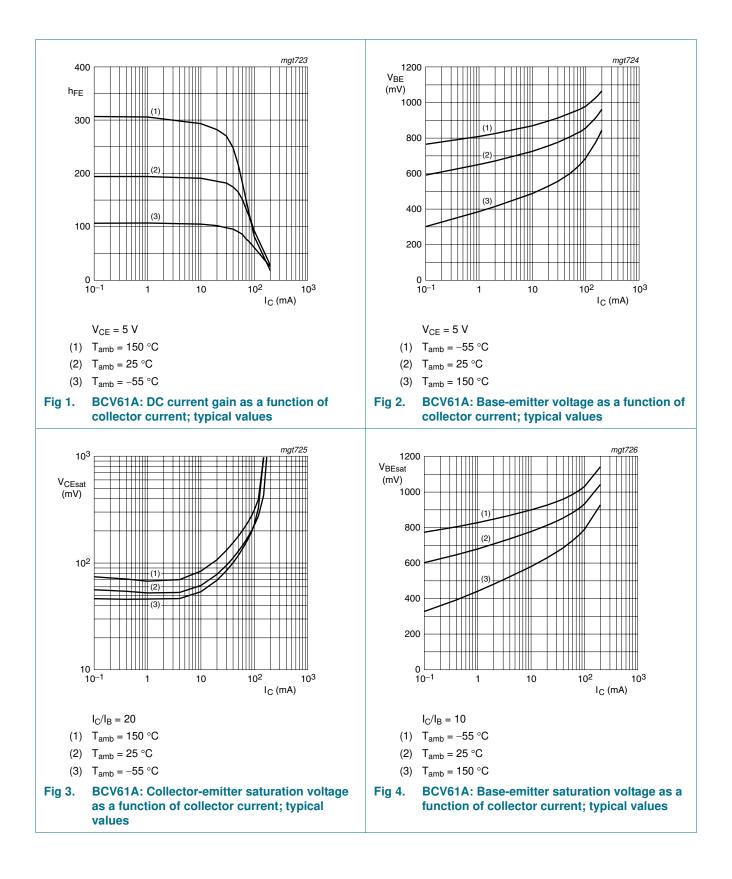
[2] V_{BE} decreases by about 2 mV/K with increasing temperature.

[3] Device, without emitter resistors, mounted on an FR4 PCB.

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NPN general-purpose double transistors

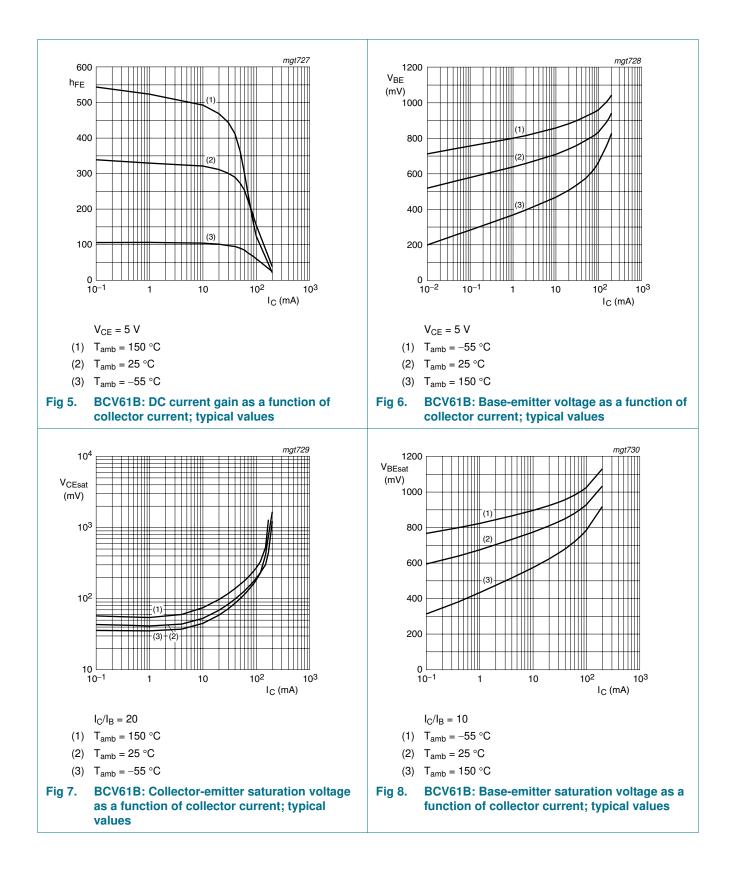
BCV61



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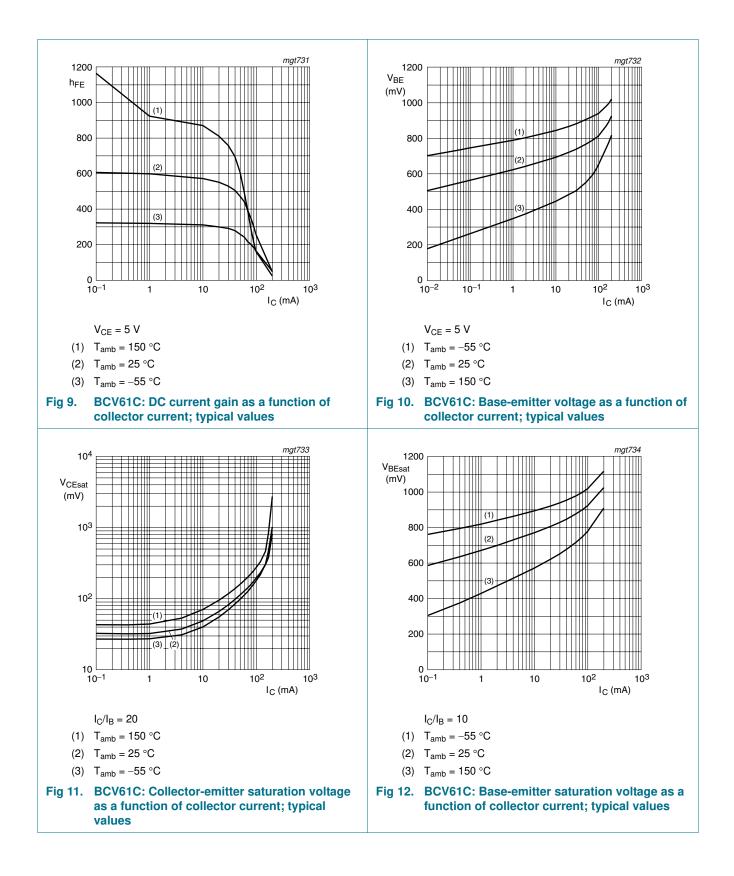
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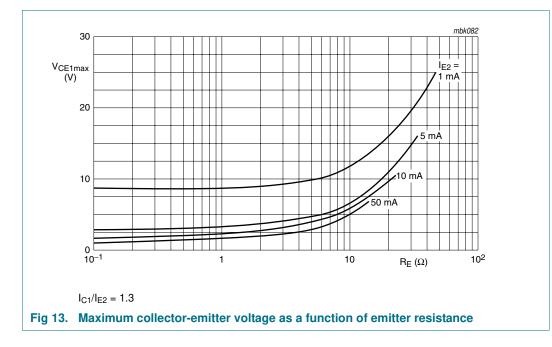
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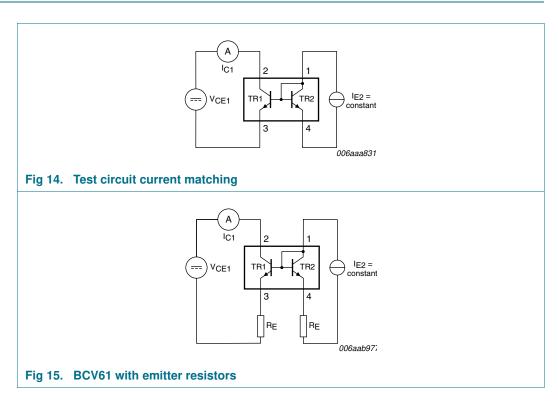


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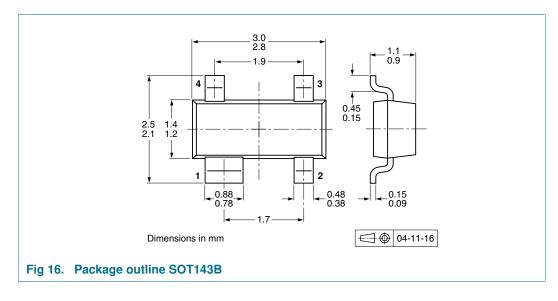
NPN general-purpose double transistors



8. Test information



9. Package outline



10. Packing information

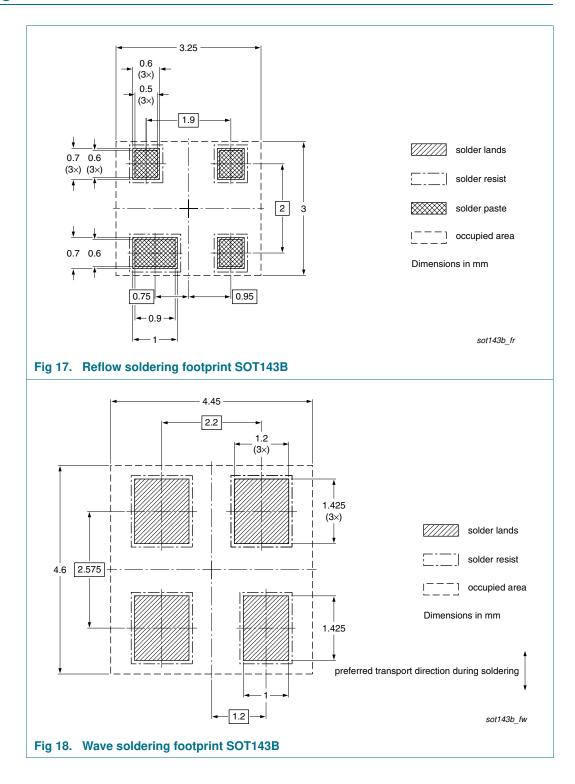
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description		Packing quantity		
				3000	10000	
BCV61	SOT143B	4 mm pitch, 8 mm tape and reel		-215	-235	
BCV61A						
BCV61B						
BCV61C						

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

11. Soldering



12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
BCV61_4	20091218	Product data sheet	-	BCV61_3			
Modifications:		of this data sheet has been of NXP Semiconductors.	redesigned to comply v	vith the new identit			
	 Legal texts 	 Legal texts have been adapted to the new company name where appropriate. 					
	Section 3 "	Section 3 "Ordering information": added					
	 Section 4 "I 	Marking": updated					
	 Figure 1, 2, 	<u>3, 4, 5, 6, 7, 8, 9, 10, 11</u> an	d <u>12</u> : added				
	Section 8 "Test information": added						
	 Figure 16: superseded by minimized package outline drawing 						
	Section 10 "Packing information": added						
	<u>Section 11 "Soldering"</u> : added						
	<u>Section 13</u>	"Legal information": update	d				
BCV61_3	19990408	Product specification	-	BCV61_CNV_2			
BCV61 CNV 2	19970616	Product specification	-	-			

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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BCV61

NPN general-purpose double transistors

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